

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor built-in Transistor)

RN2101, RN2102, RN2103 RN2104, RN2105, RN2106

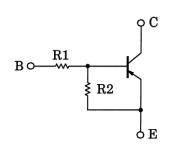
Switching, Inverter Circuit, Interface Circuit and Driver Circuit

Unit: mm

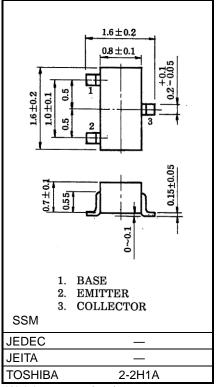
- AEC-Q101 Qualified (Note1)
- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process and miniaturize equipment.
- Various resistance values are available to suit various circuit designs.
- Complementary to RN1101 to RN1106

Note1: For detail information, please contact our sales representative.

Equivalent Circuit and Bias Resistor Values



Part No.	R1 (kΩ)	R2 (kΩ)
RN2101	4.7	4.7
RN2102	10	10
RN2103	22	22
RN2104	47	47
RN2105	2.2	47
RN2106	4.7	47



Weight: 2.4 mg (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN2101 to 2106	Vсво	-50	V	
Collector-emitter voltage	KN2101 t0 2100	VCEO	-50	V	
Emitter hass voltage	RN2101 to 2104	VEBO	-10	V	
Emitter-base voltage	RN2105, 2106	A ERO	-5		
Collector current		Ic	-100	mA	
Collector power dissipation	RN2101 to 2106	PC PC		mW	
Junction temperature	RN2101 10 2106	Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

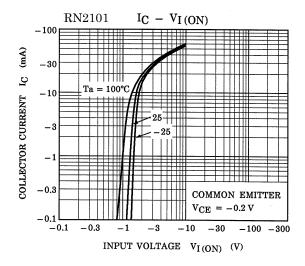
Start of commercial production 1990-12

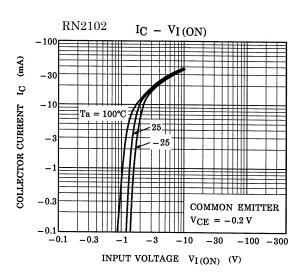


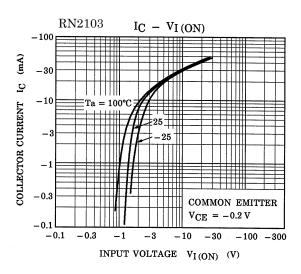
Electrical Characteristics (Ta = 25°C)

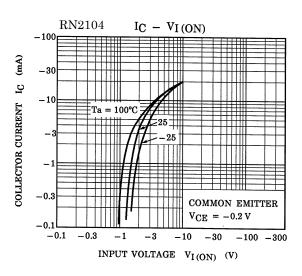
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN04044 0400	Ісво	V _{CB} = −50 V, I _E = 0 mA	_	_	-100	nA
	RN2101 to 2106	ICEO	VCE = −50 V, IB = 0 mA	_	_	-500	
Emitter cut-off current	RN2101	IEBO	VEB = −10 V, IC = 0 mA	-0.82	_	-1.52	mA
	RN2102			-0.38	_	-0.71	
	RN2103			-0.17	_	-0.33	
	RN2104			-0.082	_	-0.15	
	RN2105			-0.078	_	-0.145	
	RN2106		$V_{EB} = -5 \text{ V}, I_{C} = 0 \text{ mA}$	-0.074	_	-0.138	
	RN2101			30	_	_	
	RN2102			50	_	_	
	RN2103			70	_	_	
DC current gain	RN2104	hFE	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	80	_	_	
	RN2105			80	_	_	
	RN2106			80	_	_	
Collector-emitter saturation voltage	RN2101 to 2106	VCE (sat)	IC = -5 mA, IB = -0.25 mA	_	-0.1	-0.3	٧
	RN2101	Vi (ON)	$V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$	-1.1	_	-2.0	V
	RN2102			-1.2	_	-2.4	
	RN2103			-1.3	_	-3.0	
Input voltage (ON)	RN2104			-1.5	_	-5.0	
	RN2105			-0.6	_	-1.1	
	RN2106			-0.7		-1.3	
Leavet coally are (OFF)	RN2101 to 2104	VI (OFF)	V _{CE} = -5 V, I _C = -0.1 mA	-1.0	_	-1.5	- V
Input voltage (OFF)	RN2105, 2106			-0.5	_	-0.8	
Transition frequency	RN2101 to 2106	f⊤	V _{CE} = −10 V, I _C = −5 mA	_	200	_	MHz
Collector Output capacitance	RN2101 to 2106	C _{ob}	V _{CB} = -10 V, I _E = 0 mA, f = 1 MHz	_	3	6	pF
Input resistor	RN2101	R1	_	3.29	4.7	6.11	
	RN2102			7	10	13	kΩ
	RN2103			15.4	22	28.6	
	RN2104			32.9	47	61.1	
	RN2105			1.54	2.2	2.86	
	RN2106			3.29	4.7	6.11	
Resistor ratio	RN2101 to 2104		_	0.9	1.0	1.1	
	RN2105	R1/R2		0.0421	0.0468	0.0515	_
	RN2106			0.09	0.1	0.11	

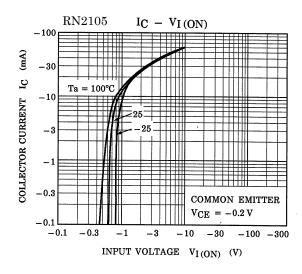


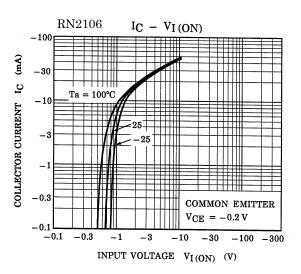






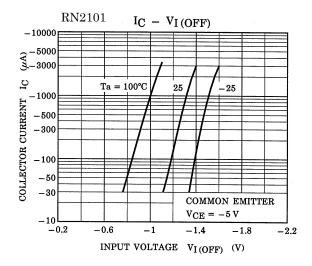


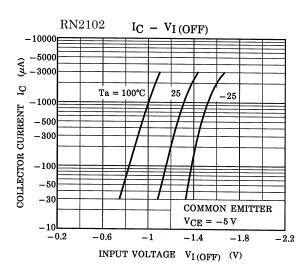


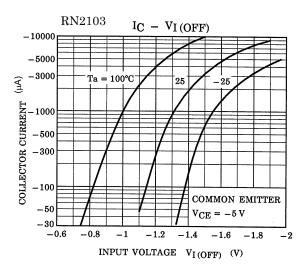


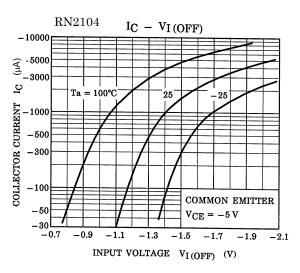
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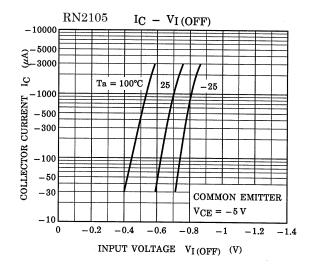


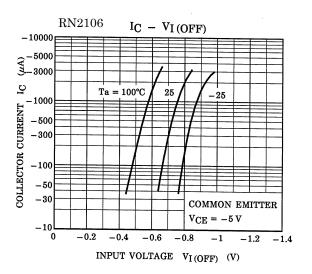






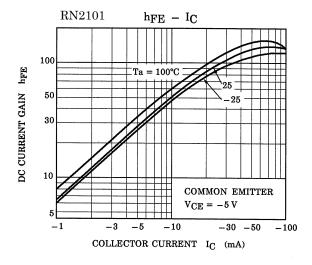


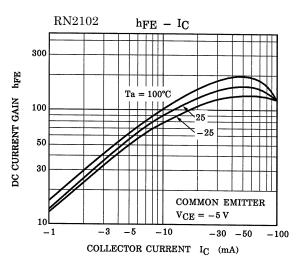


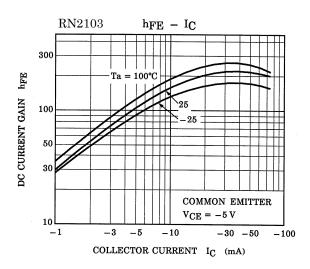


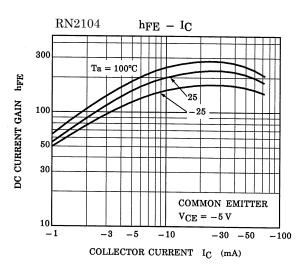
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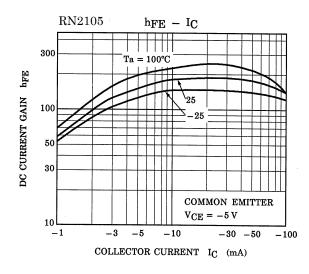


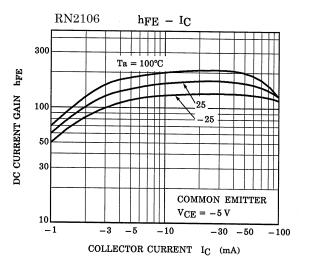






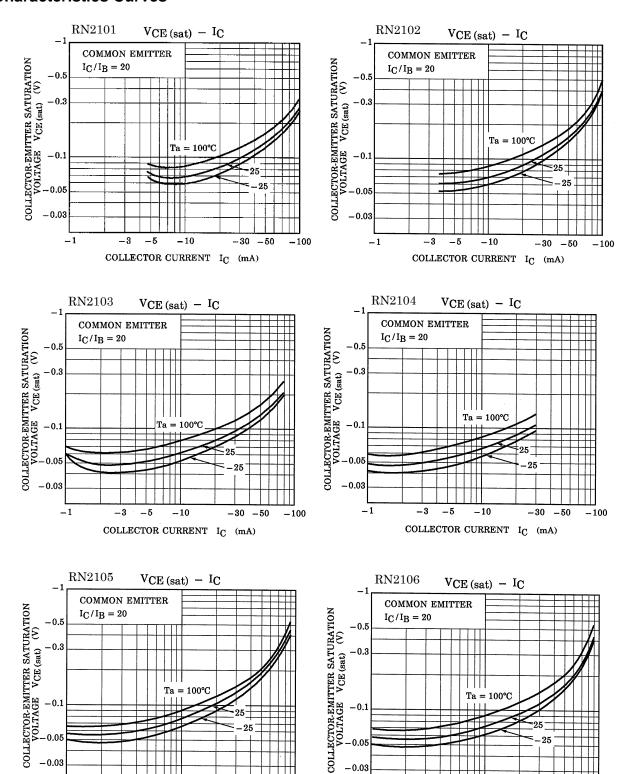






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-0.03

-1

-10

COLLECTOR CURRENT IC (mA)

-30

-10

COLLECTOR CURRENT IC (mA)

-30 -50

-0.03

-1

2019-12-04



Marking

Part No.	Marking	
RN2101	Part No.(abbreviation code)	
RN2102	Part No.(abbreviation code)	
RN2103	Part No.(abbreviation code)	
RN2104	Part No.(abbreviation code)	
RN2105	Part No.(abbreviation code)	
RN2106	Part No.(abbreviation code)	



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